

Data Sheet July 25, 2005 FN9087.2

# High Voltage Bootstrap High Side Driver

The ISL6801 is a single monolithic, inverting bootstrap driver. Its floating Level Shifter Section is optimized for the control of N-Channel Power MOSFETs in high side configurations with Bus Voltages up to 120VDC from a 5V Controller Output. It features two output stages pinned out separately to allow independent control of rise and fall times. To ensure static DC operation an integrated recharge path charges the bootstrap cap while the driver is switched off. A pull-up resistor forces the input low when no control signal is applied. The supply voltage is monitored to guarantee faultless operation at start-up.

### **Ordering Information**

| PART NUMBER | TEMP.<br>RANGE (°C) | PACKAGE                    | PKG.<br>DWG.# |
|-------------|---------------------|----------------------------|---------------|
| ISL6801AB   | -40 to 125          | 8 Ld SOIC                  | M8.15         |
| ISL6801AB-T | -40 to 125          | 8 Ld SOIC Tape<br>and Reel | M8.15         |

#### **Features**

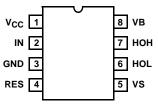
- · Active Low Input
- Separate Reset Input
- · Recharge Path for Static Operation
- Separate High and Low Gate Drive Outputs Allow Independent Turn ON/OFF Time Control
- · Supply Undervoltage Protection
- · Space Saving SO-8 Package
- Wide Operating Temperature Range

### **Applications**

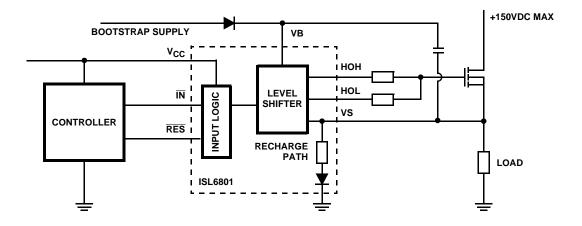
- Driver for N-Channel MOSFETs in High Side Configurations that Control Ground Referenced Loads
- Drives Solenoids, Motors, Relays and Lamps in Automotive Applications

### **Pinout**

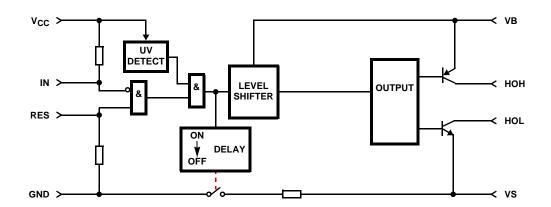
SL6801AB (SOIC) TOP VIEW



# Typical Application Block Diagram



# Functional Block Diagram



# Pin Descriptions

| PIN NUMBER | SYMBOL          | DESCRIPTION                          |  |  |
|------------|-----------------|--------------------------------------|--|--|
| 1          | V <sub>CC</sub> | Driver Supply, Typical 5.0V          |  |  |
| 2          | IN              | Driver Control Signal Input          |  |  |
| 3          | GND             | Ground                               |  |  |
| 4          | RES             | Driver Enable Signal Input ('RESET') |  |  |
| 5          | VS              | MOSFET Source Connection             |  |  |
| 6          | HOL             | MOSFET Gate Low Connection           |  |  |
| 7          | НОН             | MOSFET Gate High Connection          |  |  |
| 8          | VB              | Driver Output Stage Supply           |  |  |

#### NOTE:

The HOL and HOH are the low respective high gate drive output pins. The turn on and turn off time of the external MOSFET could be controlled by using different resistance values for high and low signal.

### **Absolute Maximum Ratings**

| Supply Voltage, V <sub>CC</sub>                                   |
|---|
| Driver Output Stage Voltage, V <sub>B</sub> (Referred to GND)130V |
| Source Reference Voltage, V <sub>S</sub>                          |
| (-5V for 0.5ms, MOSFET Off) (Min) -1.5V                           |
| (Max) 120V  |
| ESD Rating, V <sub>ESD</sub>                                      |
| Human Body Model (Min) 820V                                       |
| (Per MIL-STD-883 Method 3015.7)                                   |

### **Thermal Information**

| SOIC Package  | Thermal Resistance (Typical, Note 1)           | θ <sub>JA</sub> (°C/W)                 |
|---|--|--|
| Maximum Storage Temperature Range55°C to 150°C Maximum Lead Temperature (Soldering 10s) | SOIC Package                                   | 90                                     |
| Maximum Lead Temperature (Soldering 10s)245°C   | Maximum Junction Temperature (Plastic Package) | 150 <sup>0</sup> C                     |
| Maximum Lead Temperature (Soldering 10s)245°C   | Maximum Storage Temperature Range5             | 5 <sup>0</sup> C to 150 <sup>0</sup> C |
| (SOIC Lead Tips Only)   |  |  |
|   | (SOIC Lead Tips Only)                          |  |

## **Operating Conditions**

Temperature Range....-40°C to 125°C Supply Voltage Range (Max).....4.5V to 6.5V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1.  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

## **Electrical Specifications** All values are over full temperature range.

| PARAMETER   | SYMBOL                           | TEST CONDITIONS   | MIN  | TYP | MAX             | UNITS |
|---|----------------------------------|---|------|-----|-----------------|-------|
| Operating Temperature Range                                 | T <sub>A</sub>                   |   | -40  | -   | 125             | οС    |
| Source Reference Voltage                                    | VS                               | -1.8V Continuous, VB/V $_{OH}$ must stay low, IN = 0V, RES = 5V, V $_{CC}$ = 4.5V and 6.5V, VB = 5V and 12V, (Load R = $50\Omega$ , C = $6.8nF$ ) $T_A$ = -40 to $125^{o}C$ | -1.5 | -   | 120             | V     |
| Supply Voltage (Note 2)                                     | Vcc                              |   | 4.5  | -   | 6.5             | V     |
| Driver Output Supply  | V <sub>VB</sub> - VS             | Ident. to V <sub>GS</sub> of MOSFET Device  | 4.0  | 8.5 | 16.0            | V     |
|   | V <sub>VB</sub> - GND            | Functional  | 2.0  | -   | -               | V     |
| Switching Frequency   | f                                | Guaranteed by Design  | 100  | -   | -               | kHz   |
| Voltage Transconductance (Note 3)                           | dVs/dt                           |   | -    | -   | 500             | V/μs  |
| Peak Gate Drive Current                                     | I <sub>HOpeak</sub>              | Sink/Source Current VB = 5V and 16V, 100ns  | -    | 200 | -               | mA    |
| Continuous Gate Drive Current (Note 3) I <sub>HOcor</sub>   |                                  | Sink/Source Current Continuous  | 6.5  | 8   | -               | mA    |
| Gate Drive Level LOW VHOL, VS                               |                                  | IN at H, I <sub>HO</sub> = 1mA, VB-VS = 5V and 16V  | -    | -   | 0.3             | V     |
| Gate Drive Level LOW  | V <sub>HOL</sub> , vs            | IN at H, I <sub>HO</sub> = 100mA  | -    | -   | 2.2             | V     |
| Gate Drive Level HIGH                                       | V <sub>VB, HOH</sub>             | IN at L, I <sub>HO</sub> = 1mA, VB-VS = 5V and 16V  | -    | -   | 0.5             | V     |
| Gate Drive Level HIGH                                       | V <sub>VB</sub> , HOH            | IN at L, I <sub>HO</sub> = 100mA  | -    | -   | 2.2             | V     |
| Total IN to Output Delay (Figure 1) td <sub>IN-HOH, L</sub> |                                  | at $V_{CC}$ = 5.0V, RES = 5V,<br>Output Trigger Level: 3.5V ON at<br>VB = 5V, 1.0V OFF at VB = 16V,<br>Input 2.5V (Load R = 50 $\Omega$ , C = 6.8nF)                        | -    | 1.0 | 3.0             | μѕ    |
| Total RES to Output Delay (Figure 2)                        | td <sub>RES</sub> - HOH, L       | VB-VS = 5V and 16V,<br>(Load R = 50Ω, C = 6.8nF)  | -    | 1.0 | 3.0             | μS    |
| Output Rise/Fall Times                                      | <sup>t</sup> HOH, L<br>Fall/Rise | $VB-VS = 5V$ (Load R = $50\Omega$ , C = $6.8nF$ )   | -    | 100 | 500             | ns    |
|   |                                  | VB-VS = 16V   | -    | 200 | 500             | ns    |
|   |                                  | $VB\text{-VS} = 9.0V, \ C_{100} = 1 \mu F, \\ (Load \ R = 50 \Omega, \ C = 6.8 nF)$   | -    | 100 | 210<br>(Note 5) | mV    |

### **Electrical Specifications** All values are over full temperature range. (Continued)

| PARAMETER SYMBOL TEST CO            |                          | TEST CONDITIONS  | MIN  | TYP | MAX | UNITS |  |
|-------------------------------------|--------------------------|--|------|-----|-----|-------|--|
| VB Input Current (Note 6)           | I <sub>VB</sub>          | Static Current, VB-VS = 8.5V, $V_{CC}$ = 5V, IN = 0V, RES = 5V, (Load R = 50 $\Omega$ , C = 6.8nF)   | 300  | 750 | 875 | μА    |  |
| VB Input Current                    | I <sub>VB</sub>          | Static Current, VB-VS = 8.5V, $V_{CC}$ = 5V, $IN$ = 0V, RES = 0V, (Load R = 50 $\Omega$ , C = 6.8nF) | 100  | 550 | 700 | μА    |  |
| Driver Supply Current               | lvcc                     | at V <sub>CC</sub> = 4.5V and 6.5V<br>(Load R = 50Ω, C = 6.8nF)                                      | -    | 1.2 | 2.5 | mA    |  |
| Input Threshold LOW (Note 7)        | IN <sub>LOW</sub>        | V <sub>CC</sub> = 4.5V and 6.5V  | 1.4  | -   | -   | V     |  |
| Input Threshold HIGH (Note 7)       | IN <sub>HIGH</sub>       | V <sub>CC</sub> = 4.5V and 6.5V  | -    | -   | 3.0 | V     |  |
| Enable Threshold LOW (Note 7)       | RES <sub>LOW</sub>       | V <sub>CC</sub> = 4.5V and 6.5V  | 1.4  | -   | -   | V     |  |
| Enable Threshold HIGH (Note 7)      | RES <sub>HIGH</sub>      | V <sub>CC</sub> = 4.5V and 6.5V  |      | -   | 3.0 | V     |  |
| Input Impedance at IN               | R <sub>IN</sub>          | at $V_{CC} = 5.0V$ , RES = 5V, IN = 0V, $VB = 12V$   | 60   | 100 | 170 | kΩ    |  |
| Input Impedance at RES              | R <sub>RES</sub>         | at $V_{CC} = 5.0V$ , RES = 5V, IN = 0V, $VB = 12V$   | 60   | 100 | 170 | kΩ    |  |
| Logic Input Current at RES (Note 8) | I <sub>RES</sub>         | at Logic LOW Response HIGH   | -0.1 | -   | 1.0 | mA    |  |
| Undervoltage Shutdown Threshold     | V <sub>UV</sub>          | V <sub>CC</sub> to GND, Incl. Hyst.  | -    | 3.5 | -   | V     |  |
| Recharge Resistance (Note 9)        | R <sub>recharge</sub>    | VB = VS = HOH = HOL = 7V, RES = 5V, IN = 5V, V <sub>CC</sub> = 4.5V and 6V                           | 70   | 170 | 350 | Ω     |  |
| Recharge Turn On Delay (Note 9)     | <sup>t</sup> RechargeON  |  | 7    | 10  | 15  | μS    |  |
| Recharge Turn Off Delay             | t <sub>RechargeOFF</sub> |  | -    | -   | 1.5 | μS    |  |
| Recharge Path Voltage Drop          | Vdrop                    | at a Constant Current of 1.0mA   | -    | -   | 0.8 | V     |  |
|                                     | Recharge                 | at a Constant Current of 10mA  | -    | -   | 3.5 | V     |  |

#### NOTES:

- 2. Shutdown between 3.5V and 4.5V.
- 3. Parametric limits are guaranteed by design, but not tested in production.
- 4. The drop voltage is caused by VB to VS current flow during switching. See Figure 3.
- 5. Assuming  $3\mu s$  switching overlap, time delay use at testing  $100\mu s$ .
- 6. External MOSFET ON or OFF.
- 7. Input and Enable thresholds tested at  $V_{CC} = 4.5V$  and 6.5V, VB = 12V, VS = 0V, IN at 0V, Response RES at 5.0V.
- 8. The defined values are to be considered as a maximum allowed value. The input stage does not need to have sink or source capability.
- 9. The recharge path has to withstand transients in the 120V range for approximately 1μs while injector turn off, causing high power dissipation in the resistor.

# **Timing Diagrams**

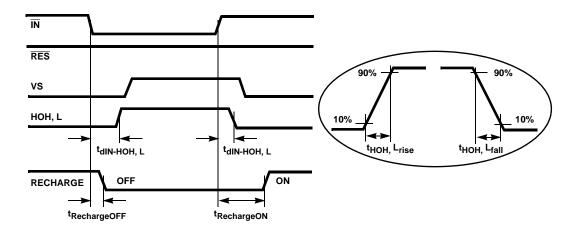


FIGURE 1. INPUT/OUTPUT TIMING DIAGRAM

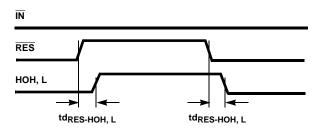
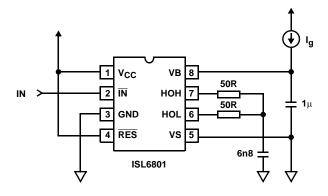
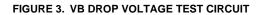


FIGURE 2. RESET TIMING DIAGRAM

# VB Drop Voltage Test





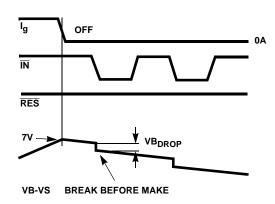
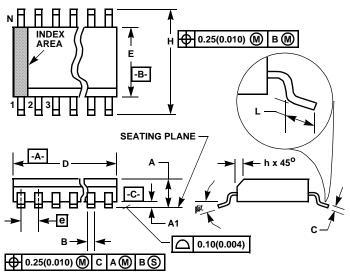


FIGURE 4. VB DROP VOLTAGE DIAGRAM

# Small Outline Plastic Packages (SOIC)



#### NOTES:

- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M8.15 (JEDEC MS-012-AA ISSUE C)
8 LEAD NARROW BODY SMALL OUTLINE PLASTIC
PACKAGE

|        | INCHES    |                | MILLIM   |                |       |
|--------|-----------|----------------|----------|----------------|-------|
| SYMBOL | MIN       | MAX            | MIN      | MAX            | NOTES |
| Α      | 0.0532    | 0.0688         | 1.35     | 1.75           | -     |
| A1     | 0.0040    | 0.0098         | 0.10     | 0.25           | -     |
| В      | 0.013     | 0.020          | 0.33     | 0.51           | 9     |
| С      | 0.0075    | 0.0098         | 0.19     | 0.25           | -     |
| D      | 0.1890    | 0.1968         | 4.80     | 5.00           | 3     |
| Е      | 0.1497    | 0.1574         | 3.80     | 4.00           | 4     |
| е      | 0.050 BSC |                | 1.27 BSC |                | -     |
| Н      | 0.2284    | 0.2440         | 5.80     | 6.20           | -     |
| h      | 0.0099    | 0.0196         | 0.25     | 0.50           | 5     |
| L      | 0.016     | 0.050          | 0.40     | 1.27           | 6     |
| N      | 8         |                | 8        | 7              |       |
| α      | 0°        | 8 <sup>0</sup> | 0°       | 8 <sup>0</sup> | -     |

Rev. 0 12/93

All Intersil U.S. products are manufactured, assembled and tested utilizing ISO9000 quality systems. Intersil Corporation's quality certifications can be viewed at www.intersil.com/design/quality

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com